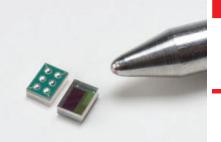
HAMAMATSU



Color sensor

S11059-01WT

I²C interface-compatible color sensor

The S11059-01WT is a color sensor that supports the I^2C (inter-integrated circuit) interface. It is sensitive to red (λ =615 nm), green (λ =530 nm), blue (λ =460 nm), and infrared (λ =855 nm) light, and outputs detected results as 16-bit digital data for each color. The photodiode for each color is automatically switched sequentially to perform measurements. The sensitivity and integration time can be adjusted so that light measurements can be performed over a wide range.

Features

- I²C interface compatible
- Sequential measurements of red, green, blue, and infrared light
- 2-step sensitivity switching (sensitivity ratio 1 : 10)
- Sensitivity adjustment by setting the integration time
- Low voltage (2.5 V or 3.3 V) operation
- Low current consumption: 75 μA typ.
- Small package (WL-CSP: wafer level-chip size package)
- Internal infrared-cut filter
- → Wide dynamic range (Low gain: 1 to 10 klx)

Feature 1 I²C interface-compatible to allow direct connection to micro-controller

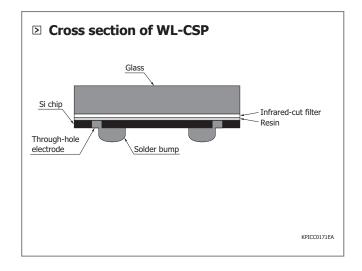
The sensor supports the I^2C interface and so can exchange data with the micro-controller using two signal lines jointly usable with other devices. The digital output makes it easy to install into electronic devices such as cell phones and flat-panel TVs whose micro-controller is compatible with the I^2C interface. The sensor supports I^2C Fast mode (400 kHz) and operates on 2.25 to 3.63 V.

Connection example of I²C interface Address 3 Address 2 Address 1 EEP ROM driver Sensor SDA SCL Micro-controller SDA: serial data SCL: serial clock

Applications

- LCD backlight adjustment for cell phones, notebook PC, etc.
- Energy-saving sensor for large-size TV, etc.
- Various types of light detection or color adjustment

The WL-CSP measures only 1.18 \times 1.68 \times 0.58 mm and lead-free reflow solder (260 °C) can be used.



→ Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Value	Unit
Supply voltage	Vdd	-0.3 to +6	V
Load current	Io	±10	mA
Power dissipation	Р	100	mW
Operating temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-40 to +100	°C
Reflow soldering conditions *1	Tsol	Peak temperature 260 °C, 3 times	-

^{*1:} Moisture absorption and reflow conditions: JEDEC J-STD-020D LEVEL2a

Recommended operating conditions

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply voltage	Vdd		2.25	-	3.63	V
I ² C bus pull-up voltage	Vbus	Rp *2=2.2 kΩ	1.65	-	Vdd + 0.5	V
High level input voltage	Vih	Vbus≥2.25 V, Vdd>2.75 V	0.7Vbus	-	Vdd + 0.5	V
(SDA, SCL)	VIII	Vbus<2.25 V, Vdd≤2.75 V	0.8Vbus	-	Vdd + 0.5	V
Low level input voltage	Vil	Vbus≥2.25 V, Vdd>2.75 V	-0.5	-	0.2Vbus	V
(SDA, SCL)	VII	Vbus<2.25 V, Vdd≤2.75 V	-0.5	-	0.3Vbus	V
Bus capacitance (SDA, SCL)	Cbus		-	-	400	pF

^{*2:} Pull-up resistor value is determined by Cbus and Vbus.

Electrical and optical characteristics

Sensor section [Ta=25 °C, Vdd=3.3 V, A light source, unless otherwise noted (initial setting: low gain, integration time: 546 ms/ch)]

Parame	ter	Symbol		Condition	Min.	Тур.	Max.	Unit			
			Blue			400 to 540					
Spectral response	rango *3	λ	Green			455 to 630		nm			
Spectral response	arige -	λ	Red			575 to 660					
		Infrared	d, more than 700 nm		785 to 885						
			Blue		-	460	-				
Peak sensitivity wa	volonath	2 m	Green		-	530	-	nm			
reak sensitivity wa	veiengui	λр	Red		-	615	-	11111			
			Infrared	d, more than 700 nm	-	855	-				
Current consumption	Operating mode	Idd	E=0 lx	(dark state),	30	75	150				
Current consumption	Standby mode	Idds	excludii	ng output current	0.1	1.0	3.0	μA			
Dark count		Sd	E=0 lx	(dark state)	-	-	5	counts			
Gain ratio		rg	High ga	in/Low gain	-	10	-	-			
		Sbl	Blue		2.01	3.35	4.69				
		Sgl	Green	Initial setting	4.57	7.61	10.66				
Dhata agnaitis its		Srl	Red	Tillual Setting	5.69	9.48	13.28				
	Low gain	Sirl	Infrared		-	1.66	-	counts//			
Photo sensitivity	Low gain	Sbl	Blue		2.51	3.35	4.19	counts/lx			
		Sgl	Green	Toiting antique *4	5.71	7.61	9.52				
		Srl	Red	Initial setting *4	7.11	9.48	11.85				
		Sirl	Infrared		-	1.66	-				
Red/Blue sensi. ratio		Srl/Sbl	Turklet -	-11:	2.12	2.83	3.54				
Red/Green sensi. ratio	Low gain	Srl/Sgl	Initial s Same c	3	0.93	1.25	1.56	-			
Blue/Green sensi. ratio		Sbl/Sgl	Jaine C	Пір	0.33	0.44	0.55				
		Sbh	Blue		19.0	31.7	44.4				
		Sgh	Green	Integration time:	45.7	76.2	106.7				
		Srh	Red	546 ms/ch	56.7	94.5	132.4				
Dhata assaitis its	Lliab asia	Sirh	Infrared		-	15.3	-				
Photo sensitivity	High gain	Sbh	Blue		23.8	31.7	39.7	counts/lx			
		Sgh	Green	Integration time:	57.2	76.2	95.3				
		Srh	Red	546 ms/ch *4	70.9	94.5	118.2				
		Sirh	Infrared		-	15.3	-	1			
Red/Blue sensi. ratio		Srh/Sbh	T t	tion time - 546 /-l-	2.24	2.98	3.73				
Red/Green sensi. ratio	High gain	Srh/Sgh		tion time: 546 ms/ch	0.93	1.24	1.55	-			
Blue/Green sensi. ratio		Sbh/Sgh	Same c	ПІР	0.31	0.42	0.52				

^{*3:} Relative sensitivity=more than 10%

^{*4:} Integration time is measured and corrected. See "Compensation method for sensitivity variation". Integration time measurement accuracy is 0.36%.



■ I²C section (Ta=25 °C, Vdd=3.3 V, unless otherwise noted)

Parameter		Symbol	Condition	Min.	Тур.	Max.	Unit
I ² C address		ADDR	7 bits)			
I ² C clock frequency		fclk		1	-	400	kHz
SDA, SCL output	High level	Voh	Rp=2.2 kΩ	0.7Vbus	-	-	V
voltage	Low level	Vol	Rp=2.2 kΩ	0	-	0.4	V
Input/output terminal of	capacitance	Ci		-	-	20	pF
SDA/SCL output fall t	ime *5	tf	Rp=2.2 kΩ, Cp=400 pF	-	-	250	ns

^{*5:} SCL/SDA output rise time is determined by a time constant of Cbus \times Rp.

Note: The I²C interface (SDA, SCL) timings conform to the "I²C bus specification version 2.1".

Register map

Adrs	Function					bit								
Auis	Tunction	7	6	5	4	3	2	1	0					
00	Control	ADC reset 1: Reset 0: Operation	Standby function 1: Standby mode 0: Operating mode	Standby function monitor	-	Gain selection 1: High gain 0: Low gain	1: Manual setting mode	(00) 87.5 µs.	time setting , (01) 1.4 ms (11) 179.2 ms					
01	Manual timing register		Integration time manual setting register (MSB)											
02	Manual tilling register	Integration time manual setting register (LSB)												
03	Sensor data register				Ou	tput data (re	d, MSB)							
04	(red)	Output data (red, LSB)												
05	Sensor data register				Out	put data (gre	en, MSB)							
06	(green)				Out	put data (gre	en, LSB)							
07	Sensor data register				Out	tput data (blu	ie, MSB)							
08	(blue)				Ou	tput data (blu	ue, LSB)							
09	Sensor data register				Outp	ut data (infra	red, MSB)							
0A	(infrared)				Outp	ut data (infra	ared, LSB)							

- Adrs 00 bit 7: Asserting this bit to "1", the ADC block is reset. The register data is not reset. To start the operation, set this bit to "0".
- Adrs 00 bit 6: Asserting this bit to "1" the device goes into standby mode. The ADC block stops its operation. The register data is not reset.

 To start the operation, set this bit to "0".
- Adrs 00 bit 5: This monitors auto standby function. "1" means standby mode. This is read only.
- Adrs 00 bit 3: Gain selection bit. "1" is high gain mode and "0" is low gain mode. This bit is selecting the photodiode area. The size ratio of high gain photodiode area and low gain photodiode area is 10:1. Therefore the gain ratio is 10 times from low to high.
- Adrs 00 bit 2: Asserting this bit to "1", the device goes into manual setting mode. Deasserting this bit to 0, goes into fixed period mode. In manual setting mode, the S11059-01WT automatically goes to standby mode after a measurement is made. In fixed period mode, measurements are continuously repeated.
- Adrs 00 bit 1,0: These bits select the period of internal basis clock. The period is equal to integration time per color in fixed period mode. "00" is 87.5 us, "01" is 1.4 ms, "10" is 22.4 ms, "11" is 179.2 ms. In manual setting mode, "00" is 175 µs, "01" is 2.8 ms, "10" is 44.8 ms, "11" is 368 ms. The integration time per color is set to multiple value (Adrs 01 & 02) with the period.
- Adrs 01 & 02: This is a multiple value setting in manual setting mode, and can be set to a minimum of 0x0000 and a maximum of 0xFFFF (65535). This is used to set how far to expand the integration time per color which specified by "Integration time setting" (Tint). For example, if you want to set the integration time per color to 546 ms, set 175 µs by Tint="00" and then set this register to N=3120 (0xC30).

Mode	Manual timing register	Integration time setting (Tint)								
Mode	(Adrs 01 & 02)	00	01	10	11					
Fixed period mode	Disabled	87.5 μs	1.4 ms	22.4 ms	179.2 ms					
Manual setting mode	N	175 × N μs	2.8 × N ms	44.8 × N ms	358.4 × N ms					

Adrs 03 to 0A: These bytes are register for sensor data. S11059-01WT measurement result is stored in these registers when the I²C command is changed to read mode. The values are kept until next read cycle.

Initial setting [Low gain, manual setting mode, Tint=00 (175 μs), integartion time 546 ms/ch]

Adrs Function		bit												
Adrs Function		7	6	5	4	3	2	1	0	Hex				
00	Control	1	1	1	-	0	1	0	0	0xE4				
01	Manual timing register	0	0	0	0	1	1	0	0	0x0C				
02			0	1	1	0	0	0	0	0x30				

S11059-01WT

- Program example

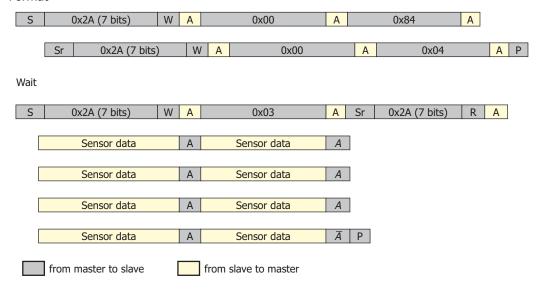
Condition 1: Initial setting [manual setting mode, low gain, Tint=00 (175 µs), integration time 546 ms/ch (0x0C30 is set in manual timing register)]

Command

Action					Data	body				Ack	Remark		
Address call (0x2A)	S	0	1	0	1	0	1	0	W	Α	7-bit address		
Register call (0x00)		0	0	0	0	0	0	0	0	Α	Calls control byte		
Register write (0x84)		1	0	0	0	0	1	0	0	Α	ADC reset, standby disabled		
Address call (0x2A)	Sr	0	1	0	1	0	1	0	W	Α	Restart, address		
Register call (0x00)		0	0	0	0	0	0	0	0	Α	Calls control byte		
Register write (0x04)		0	0	0	0	0	1	0	0	Α	P ADC reset disabled, bus release		
					Wait	longe	er tha	n inte	gratio	on time	e (>2184 ms)		
Address call (0x2A)	S	0	1	0	1	0	1	0	W	Α	7-bit address		
Register call (0x03)		0	0	0	0	0	0	1	1	Α	Calls output data byte		
Address call (0x2A)	Sr	0	1	0	1	0	1	0	R	Α	Changes to read mode		
Data read out (R: MSB))	Χ	Х	Χ	Χ	Χ	Χ	Χ	Х	Α	Red data output		
Data read out (R: LSB)		Χ	Χ	Χ	Χ	Χ	Χ	X	Χ	Α	Neu data output		
Data read out (G: MSB))	Χ	Х	Χ	Χ	Χ	Χ	Х	Х	Α	 Green data output		
Data read out (G: LSB)		Χ	Х	Χ	Χ	Χ	Χ	Χ	Х	Α	Green data output		
Data read out (B: MSB))	Χ	Х	Х	Χ	Х	Х	Х	Х	Α	Pluo data output		
Data read out (B: LSB)		Χ	Х	Х	Χ	Х	Х	Х	Х	Α	Blue data output		
Data read out (Infrared:	MSB)	Χ	Х	Χ	Χ	Χ	Χ	Χ	Х	Α	Infrared data output		
Data read out (Infrared:	LSB)	Χ	Х	Χ	Χ	Χ	Х	Х	Х	Ā	P		

S=Start condition, Sr=Restart condition, A=Acknowledge, A=Acknowledge by host, P=Stop condition, R=Read mode (1), W=Write mode (0), \overline{A} =not acknowledge

■ Format



Color sensor

S11059-01WT

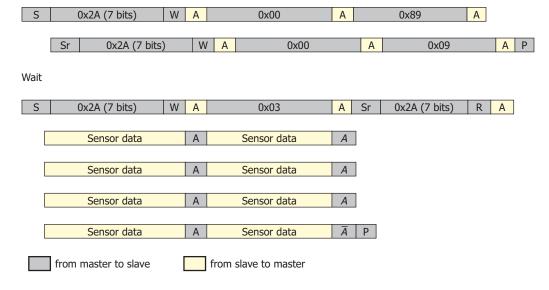
Condition 2 [fixed period mode, high gain, Tint=01 (1.4 ms), integration time 1.4 ms/ch]

Command

Communa														
Action					Data	body				Ack	Remark			
Address call (0x2A)	S	0	1	0	1	0	1	0	W	Α	7-bit address			
Register call (0x00)		0	0	0	0	0	0	0	0	Α	Calls control byte			
Register write (0x89)		1	0	0	0	1	0	0	1	Α	ADC reset, standby disabled			
Address call (0x2A)	Sr	0	1	0	1	0	1	0	W	Α	7-bit address			
Register call (0x00)		0	0	0	0	0	0	0	0	Α	Calls control byte			
Resistor write (0x09)		0	0	0	0	1	0	0	1	Α	P ADC reset disabled, bus release			
Wait I	onge	r thar	n inte	gratio	n tim	ne (>	5.6 r	ns). V	Vithir	this p	period, repeat measurement is continued.			
Address call (0x2A)	S	0	1	0	1	0	1	0	W	Α	7-bit address			
Register call (0x03)		0	0	0	0	0	0	1	1	Α	Calls output data byte			
Address call (0x2A)	Sr	0	1	0	1	0	1	0	R	Α	Changes to read mode			
Data read out (R: MSE	3)	Χ	Χ	Х	Χ	Χ	Χ	Х	Χ	Α	Red data cutput			
Data read out (R: LSB)	Х	Х	Х	Х	Х	Χ	Х	Х	Α	Red data output			
Data read out (G: MSE	3)	Χ	Х	Х	Х	Х	Х	Х	Х	Α	Croon data output			
Data read out (G: LSB)	Χ	Х	Х	Х	Х	Χ	Х	Х	Α	Green data output			
Data read out (B: MSE	3)	Х	Χ	Х	Х	Х	Χ	Х	Χ	Α	Dive data sutrout			
Data read out (B: LSB))	Х	Х	Х	Х	Х	Χ	Х	Х	Α	Blue data output			
Data read out (Infrared:	MSB)	Х	Х	Х	Х	Х	Χ	Х	Х	Α	Infrared data output			
Data read out (Infrared:	LSB)	Х	Х	Х	Х	Х	Х	Х	Х	Ā	P			

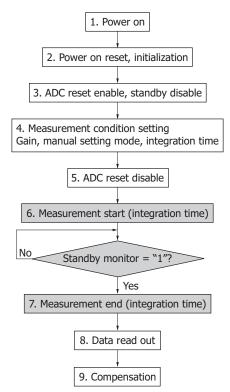
S=Start condition, Sr=Restart condition, A=Acknowledge, A=Acknowledge by host, P=Stop condition, R=Read mode(1), W=Write mode(0), \overline{A} =not acknowledge

Format



S11059-01WT

Compensation method for sensitivity variation



Sensitivity variation can be decreased using the compensation coefficient which is calculated from the integration time measurement result. Explanation of compensation method is shown as follows.

Integration time measurement method

In case of integration time measurement, it is necessary to set manual setting mode. The integration time measurement starts after "ADC reset" disabled. To measure the finishing integration time (measurement) Tmeas, check "Standby monitor" bit until it becomes to "1".

Compensation method

The sensitivity compensation that used integration time is as follows:

$$K = \frac{Tset}{Tmeas}$$

$$S' = S \cdot K$$

K : compensation coefficient
Tset : integration time (setting)
Tmeas: integration time (measurement)
S : photo sensitivity (measurement)
S' : photo sensitivity (compensation)

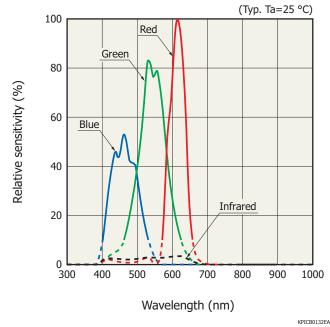
Measurement accuracy of integration time

The measurement minimum resolution of Tmeas is defined by the looping duration (Tunit). In case of default setting, the Tset is 2184 ms and assuming the Tunit to 7.8 ms, the accuracy of integration time is calulated by following formula.

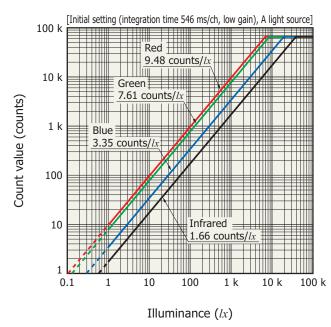
$$\frac{\text{Tunit}}{\text{Tset}} \times 100 = \frac{7.8}{2184} \times 100 = 0.36\%$$

The specification of compensated sensitivity is defined as 0.36% accuracy.

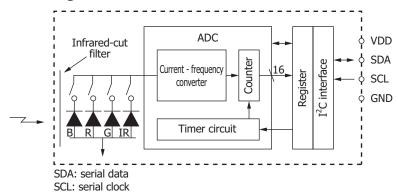
Spectral response



Count value vs. illuminance (typical example)

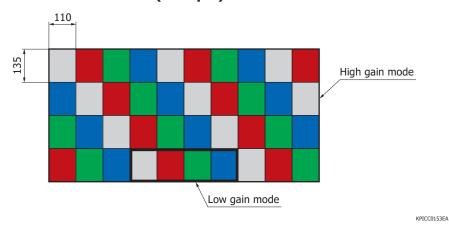


Block diagram

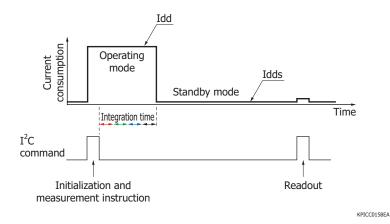


KPICC0152EA

- Details of active area (unit: μm)



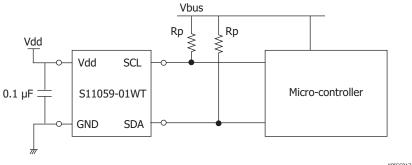
- Timing chart of standby function



HAMAMATSU

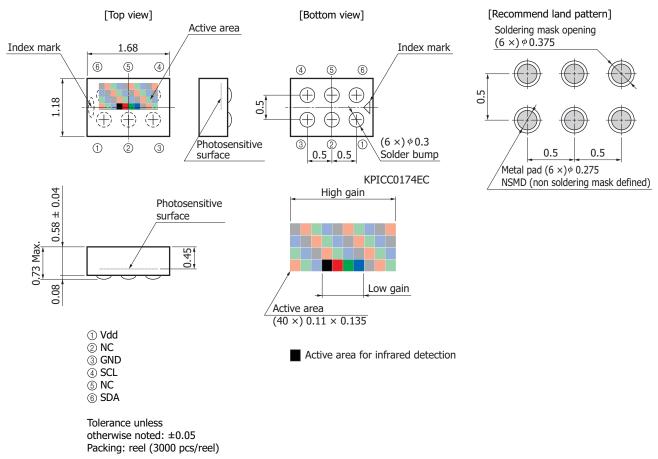
S11059-01WT

- Connection example



KPICC0174EC

Dimensional outline (unit: mm)



KPICA0081EB

8

Note: When using this product, please request our technical information (S11059 series) and ensure appropriate design according to the information.

Line-up of RGB color sensors

Type No.	Туре	Active area size (mm)	Package (mm)		Peak sensitivity wavelength (nm)			У	Photo			
S9032-02	Photodiode	ф2.0	4 × 4.8 × 1.8 ^t 6-pin (filter 0.75 ^t)	B G R	460 540 620	B G R		0.18 (A/W 0.23 (A/W 0.16 (A/W	<u>/) [</u> λ	.=54	10 nm]	
S9702	Photodiode	1.0 × 1.0	3 × 4 × 1.3 ^t 4-pin (filter 0.75 ^t)	B G R	460 540 620	B G R		0.18 (A/W 0.23 (A/W 0.16 (A/W				
S10917-35GT	Photodiode	1.0 × 1.0	3 × 1.6 × 1.0 ^t COB (on-chip filter)	B G R	460 540 620	B G R		0.2 (A/W) 0.23 (A/W) 0.17 (A/W)				
S10942-01CT	Photodiode	1.0 × 1.0	3 × 1.6 × 1.0 ^t COB (on-chip filter)		*6	B G R		0.21 (A/W 0.25 (A/W 0.45 (A/W	/) [λ /) [λ	.=46 .=54	50 nm] 10 nm]	
S9706	Digital Photo IC	1.2 × 1.2	4 × 4.8 × 1.8 ^t 6-pin (filter 0.75 ^t)	B G R	465 540 615	Low	B G R	0.21 (LSB/lx) 0.45 (LSB/lx) 0.64 (LSB/lx)	High	B G R	1.9 (LSB/lx) 4.1 (LSB/lx) 5.8 (LSB/lx)	
S11059-01WT	I ² C interface- compatible color sensor	1.22 × 0.56	1.68 × 1.18 × 0.58 ^t WL-CSP (on-chip filter)	B G R IR	460 530 615 855	Low	B G R IR	3.35 (counts/lx) 7.61 (counts/lx) 9.48 (counts/lx) 1.66 (counts/lx)	High	B G R IR	31.7 (counts/ <i>lx</i>) 76.2 (counts/ <i>lx</i>) 94.5 (counts/ <i>lx</i>) 15.3 (counts/ <i>lx</i>)	

^{*6:} Refer to "Spectral response" of "Si photodiode S10942-01CT" datasheet.

Information described in this material is current as of January, 2011. Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information.

Type numbers of products listed in the delivery specification sheets or supplied as samples may have a suffix "(X)" which means preliminary specifications or a suffix "(Z)" which means developmental specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

HAMAMATSU

www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184
U.S.A.: Hamamatsu Corporation: 360 Foothill Road, P.O.Box 6910, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1) 908-231-1908, pax: (1) 908-231-1218
Germany: Heamamatsu Photonics Deutschland GmbH: Arzbergestr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-0, Fax: (49) 8152-265-8
France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10
United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welvyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777
North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171 41 Solna, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01
Italy: Hamamatsu Photonics Italia S.R.L.: Strada della Moia, 1 int. 6, 20020 Arese, (Milano), Italy, Telephone: (39) 02-935-81-733, Fax: (39) 02-935-81-741